## NSN 5962-01-249-1126

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-249-1126 **Body Length:** 0.640 inches **Body Width:** Between 0.360 inches and 0.420 inches **Body Height:** Between 0.045 inches and 0.090 inches **Maximum Power Dissipation Rating:** 1.02 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Electrostatic sensitive and hermetically sealed and burn in and programmable and schottky and bipolar **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** F-6 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 7.0 volts power source **Time Rating Per Chacteristic:** 75.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 flat leads Shelf Life:

Demilitarization:

**Unit Of Measure:** 

Yes - demil/mli

N/a

## NSN 5962-01-249-1126

Memory Microcircuit - Page 2 of 2



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